

SANYO Semiconductors **DATA SHEET**

An ON Semiconductor Company

LA4625 — Monolithic Linear IC 2-channel 13.5W BTL Audio Power Amplifier

Overview

The LA4625 is a 2-channel general-purpose BTL audio power amplifier provided in a miniature package. It was designed for the best possible audio quality and features an extended low band roll-off frequency provided by a newly-developed NF circuit that does not require an external capacitor. Furthermore, crosstalk, which can cause muddiness in the audio output, has been significantly reduced by both circuit and wiring pattern improvements. Thus this amplifier can provide powerful lows and clear highs.

Note that this device is pin compatible with the 20W×2-channel LA4628, and allows end products differentiated by their power rating to share the same printed circuit board.

Features

- Total output : 13.5W+13.5W (at $V_{CC} = 12V$, $R_L = 4\Omega$, THD = 10%)
- PMPO reference data : 115W×2 ($V_{CC} = 20V$, $R_L = 4\Omega$)
- High-fidelity design ($f_L < 10$ Hz, $f_H = 130$ kHz)
- Extremely low impulse noise levels
- An arbitrary amplifier startup time can be set up with external components.
- Full complement of built-in protection circuits (includes circuits that protect against shorting to V_{CC}, shorting to ground, load shorting, overvoltages and excessive temperatures)

Specifications

Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions Ratings		Unit
Maximum supply voltage	V _{CC} max	No signal	24	٧
Maximum output current	I _O peak	Per channel	3.5	Α
Allowable power dissipation	Pd max	With an arbitrarily large heat sink	32.5	W
Operating temperature	Topr		-20 to +85	°C
Storage temperature	Tstg		-40 to +150	°C

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Operating Conditions at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Recommended supply voltage	VCC		12	V
Recommended load resistance range	R _L op		4 to 8	Ω
Allowable operating supply voltage	V _{CC} op		7.2 to 20	V

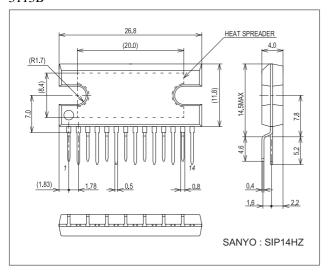
Note : With V_{CC} , R_L , and the output level in ranges such that the Pd max for the heat sink used is not exceeded.

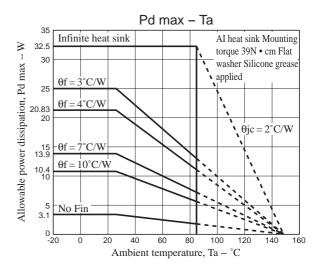
Electrical Characteristics at Ta = 25 °C, V_{CC} = 12V, R_L = 4 Ω , f = 1kHz, Rg = 600 Ω

2	0	Complete Constitues		Ratings			
Parameter	Parameter Symbol Conditions		min typ		max	Unit	
Quiescent current	Icco	Rg = 0	120	240	mA		
Standby mode current drain	I _{st}	Standby mode (amplifier off), with no power supply capacitor.		10	60	μΑ	
Voltage gain	V _G	$V_O = 0$ dBm	38	40	42	dB	
Total harmonic distortion	THD	P _O = 1W, Filter = FLAT		0.06	0.2	%	
Output power	P _O 1	THD = 10%	10	13.5		W	
Output offset voltage	V _N offset	Rg = 0	-300		+300	mV	
Output noise voltage	V _{NO}	Rg = 0, BPF = 20Hz to 20kHz		0.1	0.5	mV	
Ripple rejection ratio	SVRR	$Rg = 0, V_R = 0dBm, f_R = 100Hz$	40	50		dB	
Channel separation	CHsep	$Rg = 10k\Omega$, $V_O = 0dBm$	50	60		dB	
Input resistance	Ri		21	30	39	kΩ	
Standby pin applied voltage	VST	Amplifier on (applied through an external 10kΩ resistor)	2.5		Vcc	V	

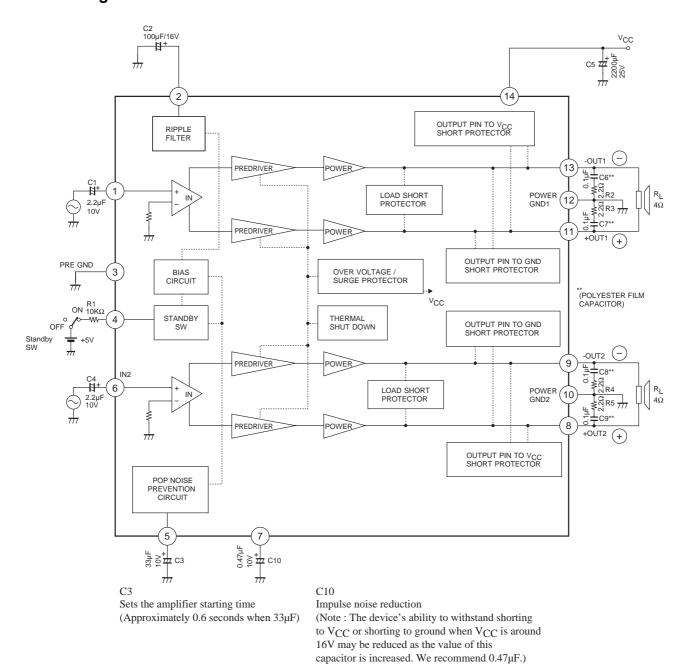
Package Dimensions

unit : mm (typ) 3113B





Block Diagram



No.6631-3/8

Pin Voltages

 V_{CC} = 12V, with 5V applied to STBY through a 10k Ω resistor, R_L = 4 Ω , R_S = 0

Pin No.	1	2	3	4	5	6	7
Pin name	IN1	DC	PRE-GND	STBY	ON TIME	IN2	POP
Pin voltage	1.46V	5.18V	0V	3.21V	2.26V	1.46V	2.05V

Pin No.	8	9	10	11	12	13	14
Pin name	+OUT2	-OUT2	PWR-GN	+OUT1	PWR-GN	-OUT1	Vcc
Pin voltage	5.21V	5.21V	0V	5.21V	0V	5.21V	12V

External Components

C1 and C4: Input capacitors. A value of $2.2\mu F$ is recommended. Determine the polarity based on the DC potential of the circuit connected directly to the LA4625 front end. Note that the low band response can be adjusted by varying fL with the capacitors C1 and C4.

C2 : Decoupling capacitor (ripple filter)

C3 : Sets the amplifier starting time, which will be approximately 0.6 seconds for a value of $33\mu F$. The starting time is proportional to the value of this capacitor, and can be set to any desired value.

C5 : Power-supply capacitor

C6, C7, C8, and C9:

Oscillation prevention capacitors. Use polyester film capacitors (Mylar capacitors) with excellent characteristics. (Note that the series resistors R2, R3, R4, and R5 are used in conjunction with these capacitors to achieve stable amplifier operation.) A value of $0.1 \mu F$ is recommended.

C10 : Impulse noise reduction capacitor. A value of $0.47\mu F$ is recommended. Caution is required when selecting the value for this capacitor, since increasing its value influences the operation of the circuits that protect against shorting the amplifier output pins to V_{CC} or to ground when higher V_{CC} voltages (approximately 16V or higher) are used.

R1 : Standby switch current limiting resistor. A value of $10k\Omega$ is recommended when a voltage in the range 2.5 to 12V will be applied as the standby switching voltage. Note that this resistor is not optional: it must be included.

IC Internal Characteristics and Notes

- 1. Standby function
 - Pin 4 is the standby switch. A voltage of 2.5V or higher must be applied through an external resistor to turn the amplifier on.
 - If a voltage of over 12V will be applied as the standby mode switching voltage, use the following formula to determine the value of R1 so that the current entering at pin 4 remains under 500μA.

$$R1 = \frac{<\!applied\ voltage\!> -1.4}{500\mu A} - 10k\Omega$$

500μA or lower

10kΩ

Applied standby voltage

About 1.4V

(2V_{BE})

Pin 4 Internal Equivalent Circuit

2. Muting function

• Pin 5 connects the capacitor that determines the starting time to prevent impulse noise. It can also be used to mute the amplifier output by shorting pin 5 to ground. When this function is used, the recovery time depends on C3.

3. Impulse noise improvements

• While the LA4625 achieves a low level of impulse noise, if even further reductions in impulse noise at power on/off (and when switching into or out of standby mode) a 0.47μF capacitor may be inserted between pin 7 and the PRE GND pin (pin 3). (Pin 7 is the output amplifier bias pin. Since the ability to withstand shorting the output pins to V_{CC} or ground is reduced for supply voltages over 16V if the pin 7 capacitance is large, we recommend a value of 0.47μF or lower for this capacitor.)

4. Protection circuits

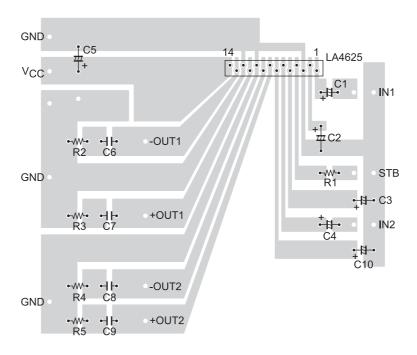
- Due to the system structure of the protection circuit for shorts to V_{CC} or ground, if there is a DC resistance between the amplifier output pins and ground, the protection circuit may operate when power is first applied and the amplifier may fail to turn on. The basic design approach we recommend is not to adopt any designs in which there is a DC resistance between the amplifier outputs and ground.
- The LA4625 includes a built-in thermal protection circuit to prevent the IC from being damaged or destroyed if abnormally high temperatures occur. This thermal protection circuit gradually reduces the output if the IC junction temperature (Tj) reaches the range 170 to 180°C due to inadequate heat sinking or other problem. If the temperature falls, the amplifier will restart automatically.
- The LA4625 also includes other protection circuits. Use of these circuits also requires care during end product design and testing.

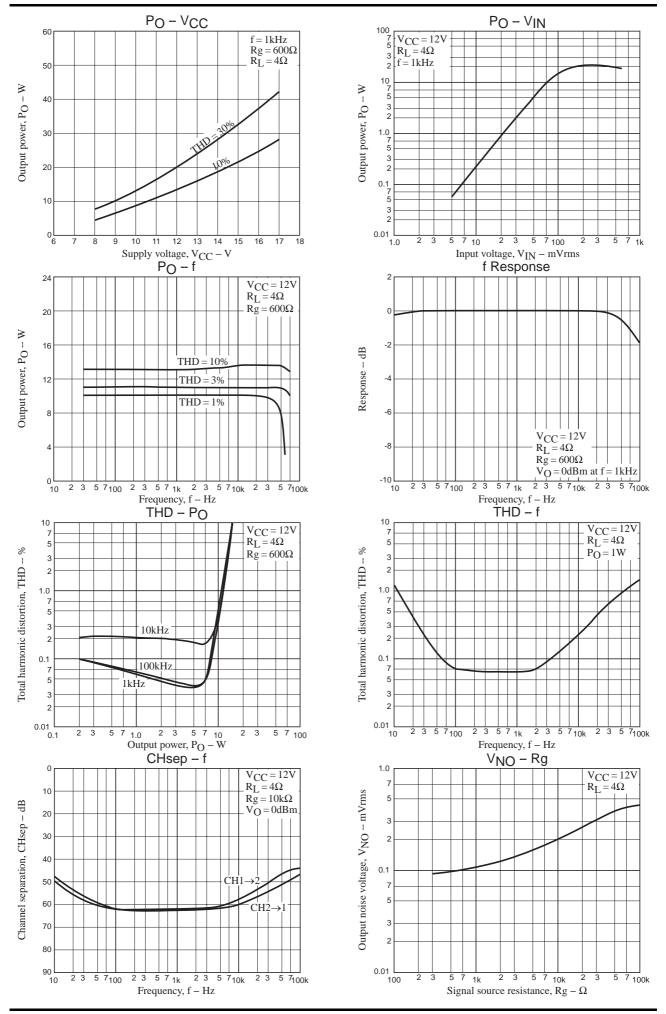
5. Other notes

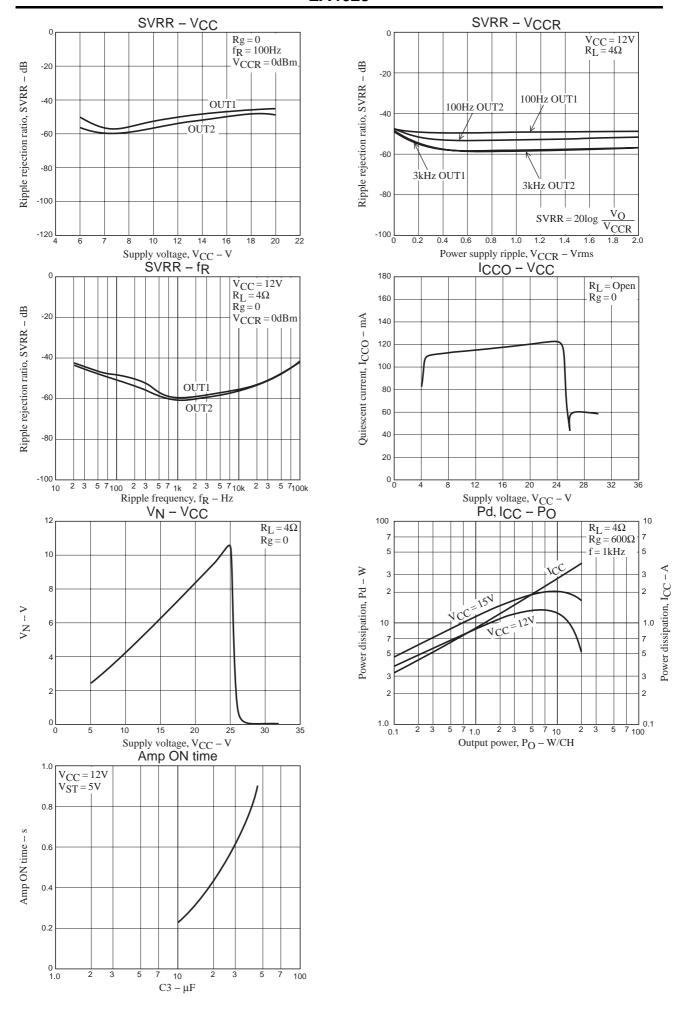
• The LA4625 is a BTL power amplifier. When testing this device, the ground systems for the test equipment connected to IC inputs, and that for the test equipment connected to IC outputs, must be isolated. Do not use a common ground.

Printed Circuit Pattern

(copper foil side)







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